Role of sulfur in BaVS3 probed by S K-edge absorption spectroscopy

Vita Ilakovac, S. Boulfaat, Yves Joly, A.M. Flank, P. Lagarde, M. Žitnik, M. Fialin, H. Berger, L. Forró

To cite this version:

HAL Id: hal-01095456
https://hal.sorbonne-universite.fr/hal-01095456
Submitted on 15 Dec 2014

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L’archive ouverte pluridisciplinaire HAL, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d’enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.
Abstract

We show that the quasi-1D behavior of BaVS$_3$ can be understood analyzing the X-ray absorption near edge spectra at the sulfur K edge. Linear dichroism experiments, analyzed with the help of \textit{ab initio} calculations, reveal two strong and polarization dependent pre-edge features, induced by the band character of the $3d$ vanadium levels. They are related to crystal field split $t_{2g}$ and $e_g$ states. When the temperature is lowered, the $t_{2g}$ feature shifts progressively to higher energy, and its intensity increases for the polarization along the $c$-axis, stacking direction of the V-S face sharing octahedra. This behavior points to the depletion of sulfur states and thus the lack of S $3p$ - V $3d$ hybridization in the direction of V-S chains.

Keywords: Metal-insulator transitions and other electronic transitions, X-ray absorption spectroscopy, Charge-density-wave system

1. Introduction

Understanding the interaction of itinerant and localized electrons is one of main challenges in solid state sciences. It determines properties of a large class of correlated systems with very rich phase diagrams, involving a subtle interplay between charge, orbital, and spin degrees of freedom [1]. The complex electronic structure of BaVS$_3$, in spite of its apparently simple quasi-1D geometry, ranks it among model compounds for the study of the competition of different ordering parameters.

BaVS$_3$ structure is constituted of chains of V-S face sharing octahedra running in $c$-direction and separated by Ba atoms [2]. The distance between neighboring V atoms along the V-S chains is less than two times shorter than the one between the chains. It could thus be considered as a quasi-1D compound. Nevertheless, its conductivity anisotropy is extremely low compared to usual quasi-1D compounds [3]. It undergoes three low temperature second order transitions. In stoichiometric BaVS$_3$, they occur at 240 K, 69 K and 30 K. The first is related to a structural change, a zigzag deformation of the V-S chains, reducing the crystal symmetry from hexagonal to orthorhombic, without altering its paramagnetic and conducting properties [2]. The metal-insulator (MI) transition at $T_{MI}$ = 69 K is accompanied by the doubling of the unit cell in the $c$ direction [4]. The pre-transitional diffuse lines, observed at the wave-vector $q_{MI}$ = 0.5 $c^*$ in x-ray diagrams, reveal the formation of the charge density waves (CDW) in V-S chains already at 170 K [5]. It is surprising that only half of active electrons directly participate to the $2k_F$ Peierls instability. Spin degrees of freedom are affected at the MI

*Corresponding author: vita.ilakovac-casses@upmc.fr
an interplay between two different types of $t_{2g}$ electron states at the Fermi level: two narrow $e(t_{2g})$ bands, and one dispersive band with mainly $d_{z^2}$ character, related to delocalized states directed along the V-S chains [10, 11, 12]. They are occupied by a single $3d^4$ electron of the formally V$^{4+}$ ion. However, according to the LDA, the delocalized $d_{z^2}$ states are nearly completely filled, which overestimates the itinerant character and fails to explain the gap opening in the insulating phase. LSDA + $U$ calculations, including a static exchange and an antiferromagnetic ordering in the (ab) plane, find a 0.15 eV gap but do not explain the paramagnetism in the metallic phase [13]. The experimental 1:1 filling ratio of the $d_{z^2}/e(t_{2g})$ states and the gap opening in the insulating phase are correctly reproduced when the correlation and exchange effects are included via dynamical mean field theory (DMFT) [14].

Already in earliest studies, it was shown that the sulfur content is determinant for BaVS$_3$ properties. Massenet et al. [16] report lowering of the $T_S$ down to 150 K and ferromagnetic behavior below 16–17 K in BaVS$_{3-\delta}$ with $\delta = 0.12$. More systematic study of magnetization, conductivity and NMR measurements are performed with a formal $\delta = 0.05, 0.10, 0.15$ and 0.20 [17]. The deficiency of about (nominal) 3% turns BaVS$_{3-\delta}$ to paramagnetic semiconductor already at room temperature. A short range 3D charge order (CO) at the wave vector $q_{CO} = (2/3, 0, \approx 1/5)_{BO}$ exists already at 300 K. Quasi-1D Peierls instability is suppressed. Instead, a long range order develops at $q_{CO}$ below 110-220 K [18, 19]. The work of Yamasaki et al. [17] confirms that below 15–18 K the sulfur deficient BaVS$_{3-\delta}$ becomes a ferromagnet.

X-ray absorption near edge spectroscopy (XANES) is an experimental tool which is able to give relevant information on both structural and electronic aspects of a studied system. The full power of this spectroscopy is used when the polarization analysis is applied on a single crystal material, as the selection rules permit to probe particular electronic states. The purpose of this paper is to show that such experiments combined with the $ab$-initio simulations reveal subtle details of the electronic structure of BaVS$_3$ in different phases of the compound. The originality of the work is in performing the measurements at the S K edge, a priori probing S 3$p$ states, while gaining insight into relative (de)localisation of V 3$d$ states, driven by the V 3$d – S 3p$ overlap.

The details of the realized S K edge polarization and temperature dependent XANES experiment on BaVS$_3$ and accompanying calculations are presented in the section 2. They are followed by the presentation of results and their interpretations in section 3 and 4, respectively.

2. Experiment and calculation details

Single crystal BaVS$_3$ samples are grown by the tellurium flux method [20]. Strong polarization dependence of the S K edge x-ray absorption spectra at room temperature (measured in the fluorescence mode) was...
observed at the ID26 beamline at ESRF. The temperature dependence was further studied at the LUCIA beamline (SOLEIL). Two samples from the same batch were mounted on a closed circle He cryostat with their needle axis (c crystal axis) either parallel or perpendicular to the scattering plane. Microsonde analysis on a SX100 CAMECA performed with 20 kV accelerated electrons did not show any notable difference in the composition of the two samples. The incident light was normal to the sample surface and polarized in the scattering plane. The two sample geometries permitted us to study two orientations relative to the incoming light polarization: \( \epsilon \parallel c \) and \( \epsilon \perp c \), \( \epsilon \) stands for experiment. The intensity of the fluorescence was measured in a total yield mode by a detector at 90° scattering angle. The inflection point of the S edge of the pure sulfur was at 2472 eV with the energy resolution of 0.3 eV. The normalization and the self-absorption correction of the spectra are performed by a code using the procedure described in ref.[21, 22].

Calculations of the room temperature spectra are performed by the Finite Difference Method Near Edge Spectroscopy (FDMNES) code [23] in the LSDA+U frame. Prior to the evaluation of the cross section, the Schrödinger equation is resolved by the finite difference method in the excited state of a 6 Å cluster embedded in a hexagonal phase BaVS\(_3\).  

3. Results

Room temperature BaVS\(_3\) S K edge XANES spectra in Fig. 1 show a very strong pre-edge doublet at 2468–2472 eV, a large structured edge feature at 2472–2484 eV and two extended structures at higher energy. The difference between the \( \epsilon \parallel c \) and \( \epsilon \perp c \) spectra is particularly strong in the pre-edge and the edge region, and becomes less important, but still existent at higher energy. We keep the pre-edge terminology because these features, often present in the S or O K-edges in metallic oxides or sulfides appear at lower energy than the corresponding edge in pure compounds.

FDMNES calculations reproduce all the features in the experimental spectra (see Fig. 2). There are however small differences in relative positions and shapes. In particular, the extended structures are slightly shifted to lower energy and the edge structure at 2480 eV is not as large as the experimental one.

The pre-edge and the edge region (2468–2484 eV) is enlarged in Fig. 3. The polarization dependence is here much more evident compared to the spectra collected at the V L edge [25]. It is worth to note that V L edge x-ray absorption spectroscopy probes V 3d states directly via dipolar transition rules, while S K edge XANES gives only an indirect insight, through V 3d – S 3p hybridization. The polarization dependence is particularly important in the region of the second pre-edge peak (2469.2 eV), where \( \sigma_\parallel - \sigma_\perp \) is much stronger compared to \( \sigma_\perp - \sigma_\parallel \). Moreover, the energy difference between the two pre-edge features, is not the same for the two geometries: \( \Delta_\parallel = 1.2 \) eV, while \( \Delta_\perp = 1.8 \) eV. The difference of the two spectra \( \sigma_\parallel - \sigma_\perp \), the linear dichroism, is shown in the same figure.

Fig. 4 shows the simulated spectra in the same energy range. The energy difference of the pre-edge peaks is \( \approx 50 \% \) larger compared to the experiment, as \( \Delta_\parallel = 2.0 \) eV and \( \Delta_\perp = 2.4 \) eV (c stands for calculation). Including electron-electron interaction of 5 eV on V– and 2 eV on S–sites improves relative intensities. It induces a partial spectral weight transfer from 2472 eV to 2476 eV and modifies the pre-peak region for \( \epsilon \parallel c \). However, it does not modify the relative shift of the two pre-edge features: \( \Delta \) is not related to the correlation gap. Decreasing the effective core-hole screening to 0.5 elec-
4. Discussion

Pre-edge structures in ligand K-edge spectra of transition metal compounds are often related to mixing of metal-ligand unoccupied states close to the Fermi level. In the case of BaVS$_3$, V 3d states overlap with S 3p states.

To understand the polarization dependence, we use Cartesian coordinates $(x, y, z)$ with $z$ along the c crystal axis. At the S K edge, quadrupolar transitions are negligible. Thus, when the polarization is along $x$, $y$, $z$, we probe respectively unoccupied 3$p_x$, 3$p_y$, 3$p_z$ sulfur states. Moreover, in the hexagonal phase of BaVS$_3$, the 3-fold axis makes that in the dipole approximation, the absorption signal is isotropic when the polarization is parallel to the basal $(x,y)$ plane, so we can distinguish only $\epsilon \parallel z$ and $\epsilon \perp z$ orientations.

The difference of the calculated spectra, $\sigma_e^u - \sigma_e^\perp$, is presented by the green line in Fig. 4. It matches well the experimental linear dichroism except in two points. First, at the very beginning of the pre-edge, the experiment shows no dichroism, while the calculated $\epsilon \parallel c$ spectra are much more dependent on the cluster size compared to the $\epsilon \perp c$ spectra, indicating that they probe more delocalized states.

The temperature dependence of the two pre-edge structures is shown in Fig. 5. For both orientations, the first pre-edge structure shifts progressively to higher energy as the temperature is lowered. From 300 K to 40 K, the total shift is $\approx 80$ meV. Moreover, for $\epsilon \parallel c$, the first pre-edge structure increases in intensity for $\approx 8\%$ as the temperature is lowered from 300 K to 100 K and remains constant below.

4. Discussion

Pre-edge structures in ligand K-edge spectra of transition metal compounds are often related to mixing of metal-ligand unoccupied states close to the Fermi level. In the case of BaVS$_3$, V 3d states overlap with S 3p states.

To understand the polarization dependence, we use Cartesian coordinates $(x, y, z)$ with $z$ along the c crystal axis. At the S K edge, quadrupolar transitions are negligible. Thus, when the polarization is along $x$, $y$, $z$, we probe respectively unoccupied 3$p_x$, 3$p_y$, 3$p_z$ sulfur states. Moreover, in the hexagonal phase of BaVS$_3$, the 3-fold axis makes that in the dipole approximation, the absorption signal is isotropic when the polarization is parallel to the basal $(x,y)$ plane, so we can distinguish only $\epsilon \parallel z$ and $\epsilon \perp z$ orientations.

The difference of the calculated spectra, $\sigma_e^u - \sigma_e^\perp$, is presented by the green line in Fig. 4. It matches well the experimental linear dichroism except in two points. First, at the very beginning of the pre-edge, the experiment shows no dichroism, while the calculated $\epsilon \parallel c$ spectra are much more dependent on the cluster size compared to the $\epsilon \perp c$ spectra, indicating that they probe more delocalized states.

The difference of the calculated spectra, $\sigma_e^u - \sigma_e^\perp$, is presented by the green line in Fig. 4. It matches well the experimental linear dichroism except in two points. First, at the very beginning of the pre-edge, the experiment shows no dichroism, while the calculated $\epsilon \parallel c$ spectra are much more dependent on the cluster size compared to the $\epsilon \perp c$ spectra, indicating that they probe more delocalized states.

The temperature dependence of the two pre-edge structures is shown in Fig. 5. For both orientations, the first pre-edge structure shifts progressively to higher energy as the temperature is lowered. From 300 K to 40 K, the total shift is $\approx 80$ meV. Moreover, for $\epsilon \parallel c$, the first pre-edge structure increases in intensity for $\approx 8\%$ as the temperature is lowered from 300 K to 100 K and remains constant below.

4. Discussion

Pre-edge structures in ligand K-edge spectra of transition metal compounds are often related to mixing of metal-ligand unoccupied states close to the Fermi level. In the case of BaVS$_3$, V 3d states overlap with S 3p states.

To understand the polarization dependence, we use Cartesian coordinates $(x, y, z)$ with $z$ along the c crystal axis. At the S K edge, quadrupolar transitions are negligible. Thus, when the polarization is along $x$, $y$, $z$, we probe respectively unoccupied 3$p_x$, 3$p_y$, 3$p_z$ sulfur states. Moreover, in the hexagonal phase of BaVS$_3$, the 3-fold axis makes that in the dipole approximation, the absorption signal is isotropic when the polarization is parallel to the basal $(x,y)$ plane, so we can distinguish only $\epsilon \parallel z$ and $\epsilon \perp z$ orientations.

The difference of the calculated spectra, $\sigma_e^u - \sigma_e^\perp$, is presented by the green line in Fig. 4. It matches well the experimental linear dichroism except in two points. First, at the very beginning of the pre-edge, the experiment shows no dichroism, while the calculated $\epsilon \parallel c$ spectra are much more dependent on the cluster size compared to the $\epsilon \perp c$ spectra, indicating that they probe more delocalized states.

The difference of the calculated spectra, $\sigma_e^u - \sigma_e^\perp$, is presented by the green line in Fig. 4. It matches well the experimental linear dichroism except in two points. First, at the very beginning of the pre-edge, the experiment shows no dichroism, while the calculated $\epsilon \parallel c$ spectra are much more dependent on the cluster size compared to the $\epsilon \perp c$ spectra, indicating that they probe more delocalized states.

The temperature dependence of the two pre-edge structures is shown in Fig. 5. For both orientations, the first pre-edge structure shifts progressively to higher energy as the temperature is lowered. From 300 K to 40 K, the total shift is $\approx 80$ meV. Moreover, for $\epsilon \parallel c$, the first pre-edge structure increases in intensity for $\approx 8\%$ as the temperature is lowered from 300 K to 100 K and remains constant below.

4. Discussion

Pre-edge structures in ligand K-edge spectra of transition metal compounds are often related to mixing of metal-ligand unoccupied states close to the Fermi level. In the case of BaVS$_3$, V 3d states overlap with S 3p states.

To understand the polarization dependence, we use Cartesian coordinates $(x, y, z)$ with $z$ along the c crystal axis. At the S K edge, quadrupolar transitions are negligible. Thus, when the polarization is along $x$, $y$, $z$, we probe respectively unoccupied 3$p_x$, 3$p_y$, 3$p_z$ sulfur states. Moreover, in the hexagonal phase of BaVS$_3$, the 3-fold axis makes that in the dipole approximation, the absorption signal is isotropic when the polarization is parallel to the basal $(x,y)$ plane, so we can distinguish only $\epsilon \parallel z$ and $\epsilon \perp z$ orientations.

The difference of the calculated spectra, $\sigma_e^u - \sigma_e^\perp$, is presented by the green line in Fig. 4. It matches well the experimental linear dichroism except in two points. First, at the very beginning of the pre-edge, the experiment shows no dichroism, while the calculated $\epsilon \parallel c$ spectra are much more dependent on the cluster size compared to the $\epsilon \perp c$ spectra, indicating that they probe more delocalized states.

The temperature dependence of the two pre-edge structures is shown in Fig. 5. For both orientations, the first pre-edge structure shifts progressively to higher energy as the temperature is lowered. From 300 K to 40 K, the total shift is $\approx 80$ meV. Moreover, for $\epsilon \parallel c$, the first pre-edge structure increases in intensity for $\approx 8\%$ as the temperature is lowered from 300 K to 100 K and remains constant below.
order transition. The temperature evolution of cell parameters indicates that the orthorhombic distortion progressively increases when the temperature is lowered [31]. It does not affect remarkably the conducting properties immediately at $T_S$ [3], but it induces a degeneracy break of the two $e(t_{2g})$ states. One of them shifts to $100$ meV higher energy (at $100$ K), while the other hybridizes strongly with $d_{z^2}$ states [15]. The depletion of $V 3d$ states with strong DOS the Fermi level, reflects in the $S$ K edge XANES as a high energy shift of the first pre-edge peak.

The first pre-edge structure as well increases in intensity for $\epsilon \parallel c$, when the temperature is lowered. This effect is related to the decrease of the $S 3p_z - V 3d_{z^2}$ hybridization, induced by the zig-zag deformation of vanadium chains. Together with the formation of charge density waves in chains in the pretransitional range (2$k_F$ fluctuations below $170$ K), it can induce semiconducting behavior already at $130$ K, the temperature which is far above the $69$ K MI transition [32].

5. Conclusion

$BaVS_3$ has attracted strong scientific interest since more than forty years, first for its mixed 1D and 3D behavior, and now as a model compound for the study of the localized/itinerant states’ interplay. Its properties still hide mysteries, in particular the question of the semiconducting behavior onset above the metal-insulator transition, and the extreme dependence of its properties on the sulfur content. This work combines $S$ K edge x-ray absorption near edge spectroscopy (XANES) and ab initio calculations in order to provide original data on the relation between sulfur and vanadium electronic states inside $V$-$S$ chains. $S$ K-edge XANES measurements reveal two strong and polarization dependent pre-edge structures, related to $S 3p$ and $V 3d$ crystal field split, $t_{2g}$ and $e_g$, states. The first feature shifts progressively to $\approx 80$ meV higher energy when the temperature is lowered from $300$ K (metallic state) to $40$ K (insulating phase). Moreover, when the incoming light polarization is parallel to the $c$-crystal axis, its intensity increases. This behavior is interpreted by the progressive depletion of $S 3p_z - V 3d_{z^2}$ hybridization due to the zig-zag deformation of $V$-$S$ octahedra chains.

6. Acknowledgments

Discussions with N. Trcera, Ph. Sainctavit, R. Nemusat and D. Cabaret are gratefully acknowledged.

References

[32] Recent structural refinements, reported by A. Arakcheeva et al. in this Proceedings, point to a new structural transition at 130K which can be responsible for the semiconducting behavior below this temperature.